

100V 7.5A Schottky Diode - SiS090T100S

Silicon Schottky Rectifier in bare die form

Version 1.0 06/04/18

Applications

- Switching Power Supply
- Converters
- Free Wheeling Diodes

Features

- Ultra Low Reverse Current
- Soft recovery low & high temperature
- Low forward Voltage drop

Electrical Characteristics

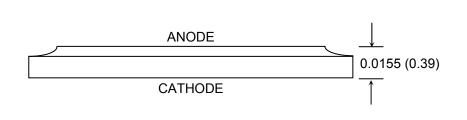
Symbol	Parameter	Conditions	Тур	Max	Unit
V_R	Reverse Voltage	-	-	100	V
		$V_R = 100V, T_J = 25^{\circ}C$	-	0.18	mA
I _R	Reverse Current	$^{1}V_{R} = 100V, T_{J} = 125^{\circ}C$	-	4.0	mA
V _F	Forward Voltage	I _F = 7.5A @ 25°C	-	0.84	V
TJ	Junction Temperature	-	-	200	°C

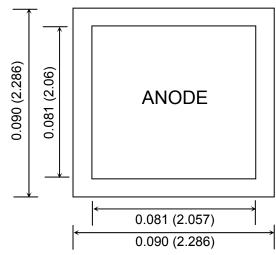
Note 1: Not production tested at wafer level, tested in package

Mechanical Data

Die Attach Method	Front Metal Composition			Back Metal Composition		
Solderable Top Solderable Back	-	TiNiAg 30kÅ	-	Ti	Ni	Ag 30kÅ

Die Drawing - Dimensions in Inches(mm)





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